

Modulbezeichnung: Scanning Electron Microscopy in Materials Science and Nanotechnology (IMN_M3/4/5/10/11-MWT_M10/11-NT_SEM) 5 ECTS
 (Scanning Electron Microscopy in Materials Science and Nanotechnology)

Modulverantwortliche/r: Erdmann Spiecker
 Lehrende: Erdmann Spiecker, Thomas Przybilla

Startsemester: WS 2020/2021 Dauer: 1 Semester Turnus: jährlich (WS)
 Präsenzzeit: 60 Std. Eigenstudium: 90 Std. Sprache: Deutsch und Englisch

Lehrveranstaltungen:

Rasterelektronenmikroskopie in Materialforschung und Nanotechnologie (WS 2020/2021, Vorlesung, 2 SWS, Erdmann Spiecker et al.)
 Übungen zur Rasterelektronenmikroskopie (WS 2020/2021, Übung, 2 SWS, Erdmann Spiecker et al.)

Inhalt:

The module focuses on the introduction to and application of Scanning Electron Microscopy (SEM) in Materials Science and Nanotechnology and comprises a lecture with corresponding exercises. Amongst others, the following topics are addressed:

- Components of an SEM instrument
- Elastic/inelastic electron-probe/sample interactions, interaction volume, generation of secondary and backscattered electrons
- Contrast mechanisms of different detector systems
- Topographic und chemically-sensitive imaging
- Electron diffraction and its application in SEM
- Scanning Transmission Electron Microscopy (STEM)
- Quantitative X-ray spectroscopy
- Focused ion beams (Dual-Beam FIB, He-ion microscopy)
- Preparation-specific challenges
- Application examples

Specific topics are accompanied with suitable exercises (e.g. Monte-Carlo simulations to simulate electron trajectories).

Lernziele und Kompetenzen:

Die Studierenden

Fachkompetenz

Wissen

- Introduction to the basic concepts of and physics behind SEM

Verstehen

- Overview over applications and deeper understanding of SEM and FIB techniques in materials science on the micro- and nanoscale
- Enhancement of knowledge through teaching of current SEM applications and state-of-the-art developments in research

Anwenden

- Application and consolidation of taught contents by SEM-related exercises

Literatur:

- Reimer, Scanning Electron Microscopy, Springer Verlag.
- Goodhews, Humphreys and Beanland: Electron Microscopy and Analysis
- Goldstein et al., Scanning Electron Microscopy and X-Ray Microanalysis (2003)
- N. Yao, Focused Ion Beam Systems, Basics and Applications, Cambridge University Press, 2010.
- L.A. Gianuzzi, F.A. Stevie, Introduction to Focused Ion Beams. Instrumentation, Theory, Techniques and Practice, Springer, 2005.

- J. Orloff, M. Utlaut, L. Swanson, High Resolution Focused Ion Beams: FIB and its Applications, Springer, 2003
- Lecture notes.

Studien-/Prüfungsleistungen:

Scanning Electron Microscopy in Materials Science and Nanotechnology (Prüfungsnummer: 62831)

(englische Bezeichnung: Scanning Electron Microscopy in Materials Science and Nanotechnology)

Prüfungsleistung, mündliche Prüfung, Dauer (in Minuten): 15

Anteil an der Berechnung der Modulnote: 100%

weitere Erläuterungen:

Prüfungssprache nach Wahl der Studierenden

Prüfungssprache: Deutsch oder Englisch

Erstablesung: WS 2020/2021, 1. Wdh.: SS 2021

1. Prüfer: Erdmann Spiecker
